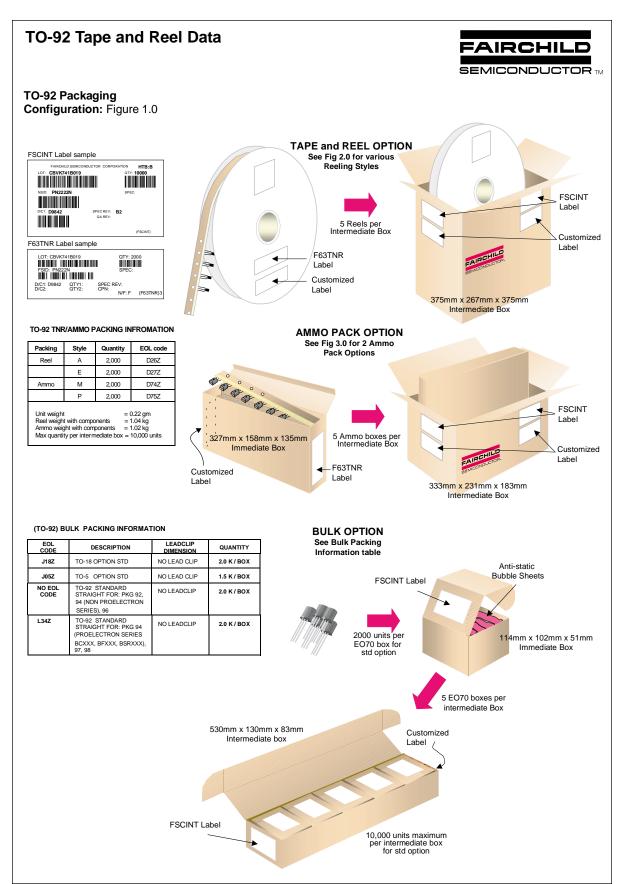
PNP Switching Transistor (continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHAI	RACTERISTICS				
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_{C} = 10 \text{ mA}, I_{B} = 0$	12		V
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	$I_C = 100 \mu A, V_{BE} = 0$	12		V
/ _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	12		V
/ _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 100 \mu A, I_C = 0$	4.0		V
CES	Collector Cutoff Current	$V_{CE} = 6.0 \text{ V}, V_{BE} = 0$		0.01	μΑ
		$V_{CE} = 6.0 \text{ V}, V_{BE} = 0, T_A = 65^{\circ}\text{C}$ $V_{CE} = 6.0 \text{ V}, V_{BE} = 0$		1.0	μΑ
В	Base Current	$V_{CE} = 6.0 \text{ V}, V_{BE} = 0$		10	nA
ON CHAR	ACTERISTICS*				
) _{FE}	DC Current Gain	$I_C = 10 \text{ mA}, V_{CE} = 0.3 \text{ V}$	30	120	
'FE	Do current dans	$I_C = 50 \text{ mA}, V_{CE} = 0.3 \text{ V}$ $I_C = 50 \text{ mA}, V_{CE} = 1.0 \text{ V}$	20	120	
/ _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$		0.3	V
		$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 1.0 \text{ mA}$		0.2	V
		$I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$ $I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}, T_A = 65^{\circ}\text{C}$		0.6 0.25	V V
/ _{BE(sat)}	Base-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}, I_A = 0.5 \text{ c}$	0.75	0.25	V
BE(sat)	Base Emilier Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 3.0 \text{ mA}$	0.8	1.0	V
		$I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$		1.5	V
SMALL SI	GNAL CHARACTERISTICS Current Gain - Bandwidth Product	$I_{C} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V},$	500		MHz
Sobo	Output Capacitance	f = 100 MHz $V_{CB} = 5.0 \text{ V}, I_{E} = 0,$		3.5	pF
J obo	Cutput Capacitance	f = 1.0 MHz		0.0	Pi
C _{ibo}	Input Capacitance	$V_{BE} = 0.5 \text{ V}, I_{C} = 0,$		3.5	pF
		f = 1.0 MHz			
SWITCHIN	NG CHARACTERISTICS				
d	Doloy Timo			40	
	Delay Time	$V_{CC} = 6.0 \text{ V}, V_{BE(off)} = 1.9 \text{ V},$		10	ns
r	Rise Time	$V_{CC} = 6.0 \text{ V}, V_{BE(off)} = 1.9 \text{ V},$ $I_{C} = 50 \text{ mA}, I_{B1} = 5.0 \text{ mA}$		30	ns ns
•	· ·	<u> </u>			
s	Rise Time	$I_C = 50 \text{ mA}, I_{B1} = 5.0 \text{ mA}$ $V_{CC} = 6.0 \text{ V}, I_C = 50 \text{ mA},$		30 20	ns
is if	Rise Time Storage Time Fall Time	$\begin{split} &I_{C} = 50 \text{ mA}, \ I_{B1} = 5.0 \text{ mA} \\ &V_{CC} = 6.0 \text{ V}, \ I_{C} = 50 \text{ mA}, \\ &I_{B1} = I_{B2} = 5.0 \text{ mA} \end{split}$		30 20 12	ns ns ns
is if	Rise Time Storage Time	$I_C = 50 \text{ mA}, I_{B1} = 5.0 \text{ mA}$ $V_{CC} = 6.0 \text{ V}, I_C = 50 \text{ mA},$		30 20	ns ns
is if	Rise Time Storage Time Fall Time	$\begin{split} I_C &= 50 \text{ mA}, \ I_{B1} = 5.0 \text{ mA} \\ V_{CC} &= 6.0 \text{ V}, \ I_C = 50 \text{ mA}, \\ I_{B1} &= I_{B2} = 5.0 \text{ mA} \\ V_{CC} &= 6.0 \text{ V}, \ V_{BE(off)} = 1.9 \text{ V}, \\ I_C &= 50 \text{ mA}, \ I_{B1} = 5.0 \text{ mA} \end{split}$		30 20 12 25	ns ns ns
s f	Rise Time Storage Time Fall Time	$\begin{split} &I_{C} = 50 \text{ mA}, \ I_{B1} = 5.0 \text{ mA} \\ &V_{CC} = 6.0 \text{ V}, \ I_{C} = 50 \text{ mA}, \\ &I_{B1} = I_{B2} = 5.0 \text{ mA} \\ &V_{CC} = 6.0 \text{ V}, \ V_{BE(off)} = 1.9 \text{ V}, \\ &I_{C} = 50 \text{ mA}, \ I_{B1} = 5.0 \text{ mA} \\ &V_{CC} = 1.5 \text{ V}, \ I_{C} = 10 \text{ mA}, \end{split}$		30 20 12	ns ns ns
is if	Rise Time Storage Time Fall Time Turn-On Time	$\begin{split} &I_{C} = 50 \text{ mA}, \ I_{B1} = 5.0 \text{ mA} \\ &V_{CC} = 6.0 \text{ V}, \ I_{C} = 50 \text{ mA}, \\ &I_{B1} = I_{B2} = 5.0 \text{ mA} \\ &V_{CC} = 6.0 \text{ V}, \ V_{BE(off)} = 1.9 \text{ V}, \\ &I_{C} = 50 \text{ mA}, \ I_{B1} = 5.0 \text{ mA} \\ &V_{CC} = 1.5 \text{ V}, \ I_{C} = 10 \text{ mA}, \\ &I_{B1} = I_{B2} = 0.5 \text{ mA} \end{split}$		30 20 12 25 60	ns ns ns ns
ts tf ton	Rise Time Storage Time Fall Time	$\begin{split} &I_{C} = 50 \text{ mA}, \ I_{B1} = 5.0 \text{ mA} \\ &V_{CC} = 6.0 \text{ V}, \ I_{C} = 50 \text{ mA}, \\ &I_{B1} = I_{B2} = 5.0 \text{ mA} \\ &V_{CC} = 6.0 \text{ V}, \ V_{BE(off)} = 1.9 \text{ V}, \\ &I_{C} = 50 \text{ mA}, \ I_{B1} = 5.0 \text{ mA} \\ &V_{CC} = 1.5 \text{ V}, \ I_{C} = 10 \text{ mA}, \\ &I_{B1} = I_{B2} = 0.5 \text{ mA} \\ &V_{CC} = 6.0 \text{ V}, \ V_{BE(off)} = 1.9 \text{ V}, \end{split}$		30 20 12 25	ns ns ns
tr ts tf ton	Rise Time Storage Time Fall Time Turn-On Time	$\begin{split} &I_{C} = 50 \text{ mA}, \ I_{B1} = 5.0 \text{ mA} \\ &V_{CC} = 6.0 \text{ V}, \ I_{C} = 50 \text{ mA}, \\ &I_{B1} = I_{B2} = 5.0 \text{ mA} \\ &V_{CC} = 6.0 \text{ V}, \ V_{BE(off)} = 1.9 \text{ V}, \\ &I_{C} = 50 \text{ mA}, \ I_{B1} = 5.0 \text{ mA} \\ &V_{CC} = 1.5 \text{ V}, \ I_{C} = 10 \text{ mA}, \\ &I_{B1} = I_{B2} = 0.5 \text{ mA} \end{split}$		30 20 12 25 60	ns ns ns ns

 $I_{B1} = I_{B2} = 0.5 \ mA$

NOTE: All voltages (V) and currents (A) are negative polarity for PNP transistors.

^{*}Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

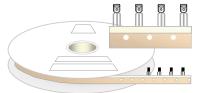


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TO-92 Tape and Reel Data, continued

TO-92 Reeling Style Configuration: Figure 2.0

Machine Option "A" (H)

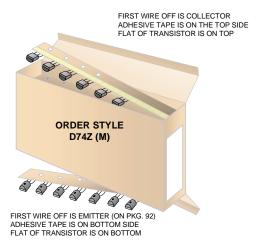


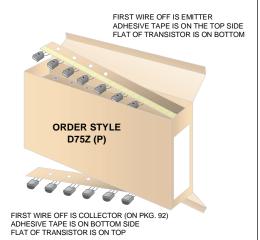
Style "A", D26Z, D70Z (s/h)

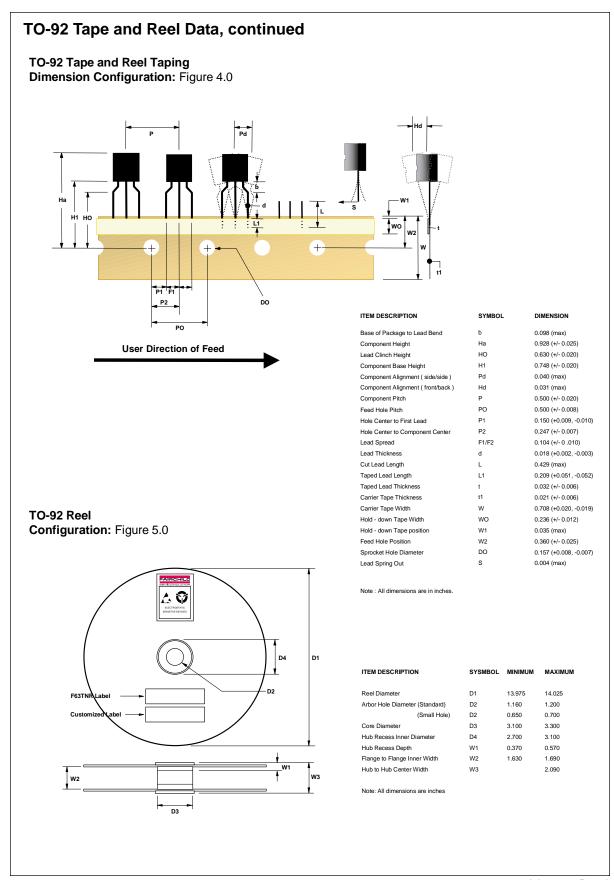
Machine Option "E" (J)

Style "E", D27Z, D71Z (s/h)

TO-92 Radial Ammo Packaging Configuration: Figure 3.0





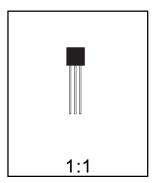


TO-92 Package Dimensions



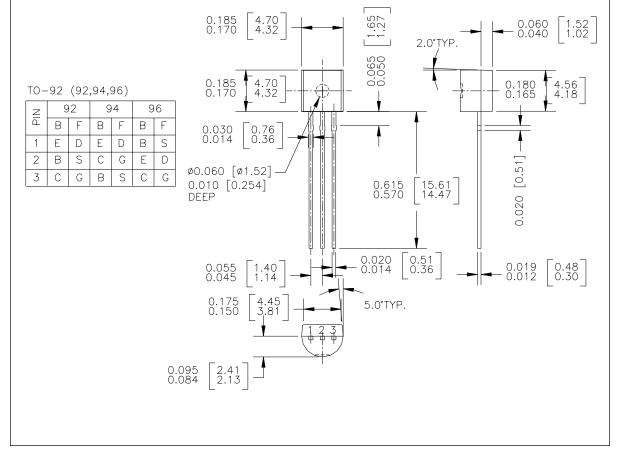
TO-92 (FS PKG Code 92, 94, 96)





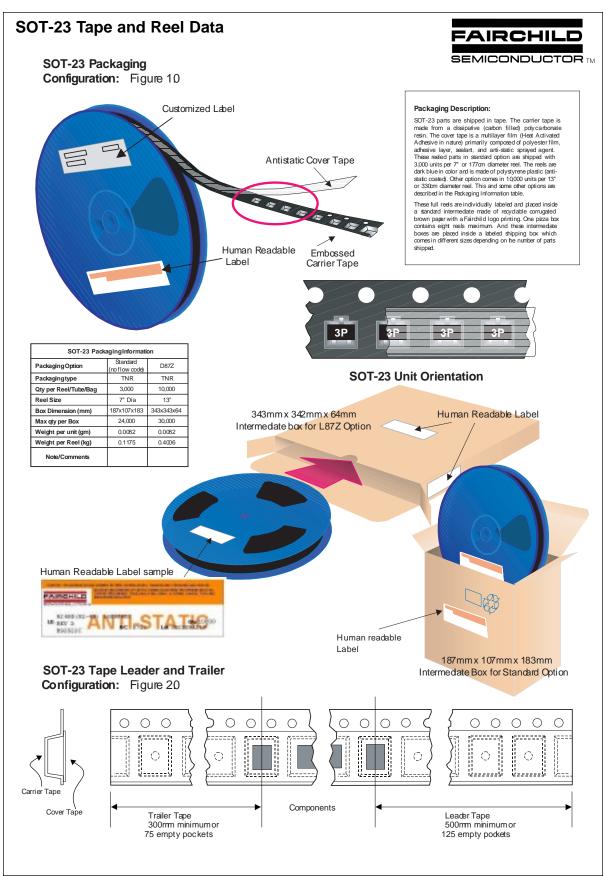
Scale 1:1 on letter size paper
Dimensions shown below are in:
inches [millimeters]

Part Weight per unit (gram): 0.1977



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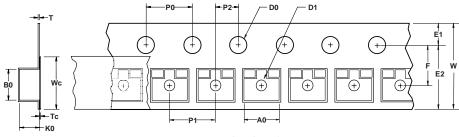
January 2000, Rev. B



SOT-23 Tape and Reel Data, continued

SOT-23 Embossed Carrier Tape

Configuration: Figure 3.0



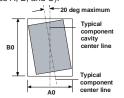
User Direction of Feed	

Dimensions are in millimeter														
Pkg type	Α0	В0	w	D0	D1	E1	E2	F	P1	P0	K0	Т	Wc	Тс
SOT-23 (8mm)	3.15 +/-0.10	2.77 +/-0.10	8.0 +/-0.3	1.55 +/-0.05	1.125 +/-0.125	1.75 +/-0.10	6.25 min	3.50 +/-0.05	4.0 +/-0.1	4.0 +/-0.1	1.30 +/-0.10	0.228 +/-0.013	5.2 +/-0.3	0.06 +/-0.02

Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



Sketch A (Side or Front Sectional View)
Component Rotation



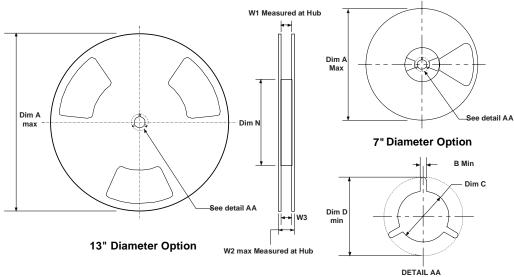
Sketch B (Top View)
Component Rotation



Sketch C (Top View)

Component lateral movement

SOT-23 Reel Configuration: Figure 4.0

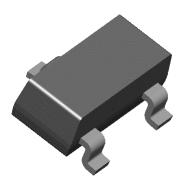


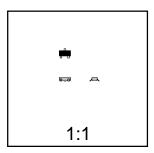
Dimensions are in inches and millimeters									
Tape Size	Reel Option	Dim A	Dim B	Dim C	Dim D	Dim N	Dim W1	Dim W2	Dim W3 (LSL-USL)
8mm	7" Dia	7.00 177.8	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	2.165 55	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9
8mm	13" Dia	13.00 330	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	4.00 100	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9

SOT-23 Package Dimensions



SOT-23 (FS PKG Code 49)

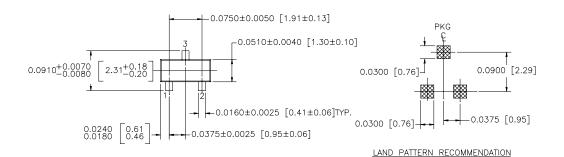


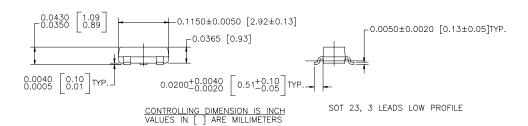


Scale 1:1 on letter size paper

Dimensions shown below are in: inches [millimeters]

Part Weight per unit (gram): 0.0082





NOTE: UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

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September 1998, Rev. A1

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DOMETM ISOPLANARTM Quiet SeriesTM E²CMOSTM MICROWIRETM SILENT SWITCHER[®]

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Rev. G